



# SVC211SPA

Diffused Junction Type Silicon Diode  
Varactor Diode (IOCAP)

for FM Low-Voltage Electronic Tuning

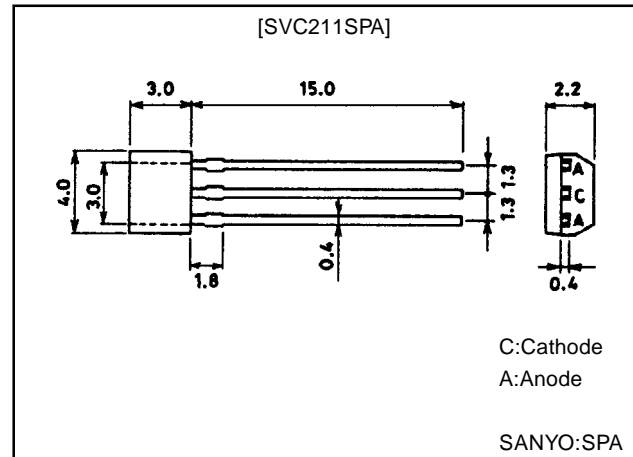
## Features

- Twin type varactor diode being excellent in large input characteristic and intended for use in high-voltage FM electronic applications.

## Package Dimensions

unit:mm

1129



## Specifications

Absolute Maximum Ratings at Ta = 25°C

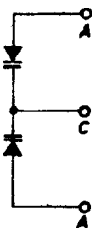
Parameter	Symbol	Conditions	Ratings	Unit
Reverse Voltage	$V_R$		-32	V
Junction Temperature	$T_J$		125	°C
Storage Temperature	$T_{stg}$		-55 to 125	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Breakdown Voltage	$V_{(BR)R}$	$I_R = -10\mu A$	-32			V
Reverse Current	$I_R$	$V_R = -30V$			-50	nA
Interterminal Capacitance*	$C_{3.0V}$	$V_R = -3.0V, f = 1MHz$	37.0		42.0	pF
	$C_{25V}$	$V_R = -25V, f = 1MHz$	14.8		18.2	pF
Capacitance Ratio*	CR	$C_{3.0V}/C_{25V}, f = 100MHz$	2.32		2.55	
Quality Factor	Q	$V_R = -3.0V, f = 100MHz$	100			

Note)\*:Capacitance value of one diode

## Electrical Connection



A:Anode  
C:Cathode

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